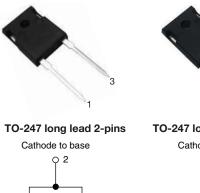
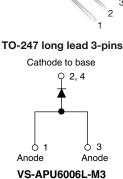
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Vishay Semiconductors

Ultrafast Soft Recovery Diode, 60 A FRED Pt®

3





VS-EPU6006L-M3

Cathode

ტ

Anode

3

PRODUCT SUMMARY						
Package	TO-247 long lead 2 pins,					
Fackage	TO-247 long lead 3 pins					
I _{F(AV)}	60 A					
V _R	600 V					
V _F at I _F	1.05 V					
t _{rr} typ.	32 ns					
T _J max.	175 °C					
Diode variation	Single die					

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification



[•] Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

VS-EPU60/VS-APU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current in DC	I _{F(AV)}	T _C = 116 °C	60	٨			
Single pulse forward current	I _{FSM}	T _C = 25 °C	600	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage	V _F	I _F = 60 A	-	1.2	1.5	V
		$I_F = 60 \text{ A}, \text{T}_\text{J} = 125 \ ^\circ\text{C}$	-	1.1	1.3	
		I _F = 60 A, T _J = 175 °C	-	1.05	1.2	
		V _R = V _R rated	-	0.2	30	
Reverse leakage current	I _R	$T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	-	200	μΑ
Junction capacitance	CT	V _R = 600 V	-	38	-	pF

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 20$	00 A/µs, V _R = 30 V	-	32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	110	-	ns	
		T _J = 125 °C	I _F = 60 A dI _F /dt = 200 A/µs V _R = 200 V	-	200	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	10	-	^	
		T _J = 125 °C		-	19	-	A	
Reverse recovery charge	0	T _J = 25 °C		-	530	-		
	Q _{rr}	T _J = 125 °C		-	1900	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	-	0.65	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	-
Weight			-	6	-	g
Weight			-	0.21	-	oz.
Mounting torque			6 (5)	-	1.2 (10)	kgf. cm (lbf ⋅ in)
Marking dayling		Case style TO-247 long lead 2 pins	EPU6006L			-
Marking device		Case style TO-247 long lead 3 pins		APU	6006L	



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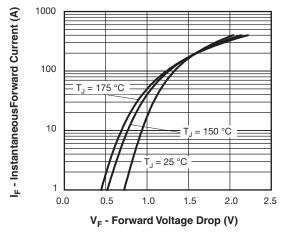


Fig. 1 - Typical Forward Voltage Drop Characteristics

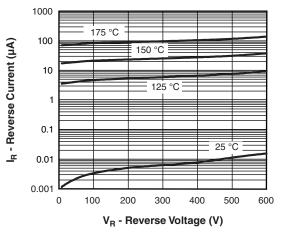


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

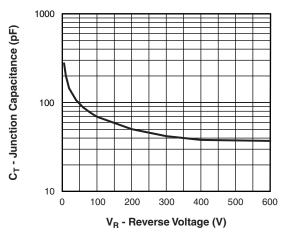


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

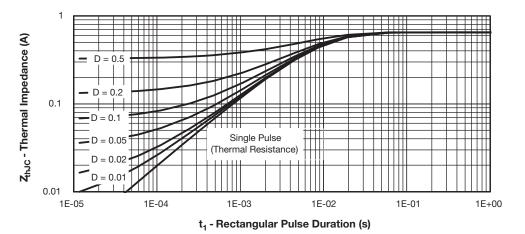
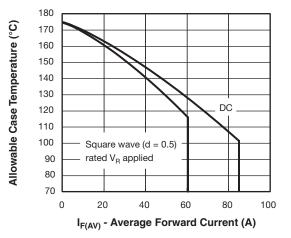


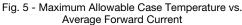
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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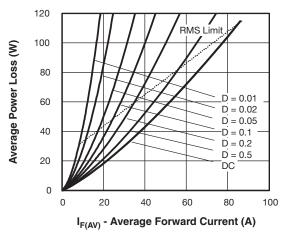


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

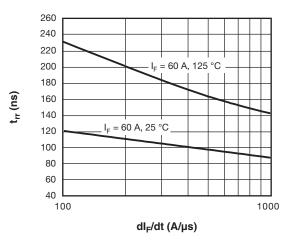


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

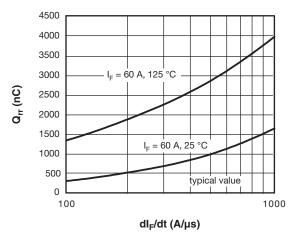
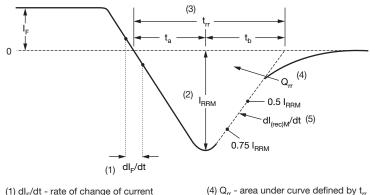


Fig. 8 - Typical Stored Charge vs. dl_F/dt



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- (1) dl_F/dt rate of change of current through zero crossing
- (4) Q_m area under curve defined by t_n and I_{RRM}
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

 $Q_{rr} = \frac{t_{rr} \times I_{BBM}}{2}$

(5) dl_{(rec)M}/dt - peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code

e	VS-	Е	Ρ	U	60	06	L	-M3	
	1	2	3	4	5	6	7	8	
	1 -	Visł	nay Sem	niconduc	ctors pro	oduct			
	 Circuit configuration: A = single diode 3-pin E = single diode 2-pin 								
	3 -	P =	P = TO-247						
	4 -	- U =	U = ultrafast recovery time						
	5 -	- Current code (60 = 60 A)							
	6 -	- Volt	Voltage code (06 = 600 V)						
	7 -	L =	long lea	d					
	8 -	Env	ironmer	ntal digit:	:				

-M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTI						
VS-EPU6006L-M3	30	300	Antistatic plastic tube			
VS-APU6006L-M3	30	300	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensione	www.vishay.com/doc?95599				
Dimensions	TO-247AC 2-pin LL	www.vishay.com/doc?95598			
Port marking information	TO-247 3-pin LL	www.vishay.com/doc?95593			
Part marking information	TO-247 2-pin LL	www.vishay.com/doc?95592			

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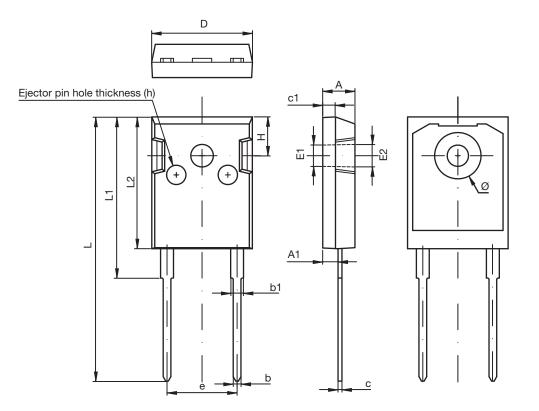


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TO-247 2 Pin Long Lead

DIMENSIONS in millimeters

ISHAY



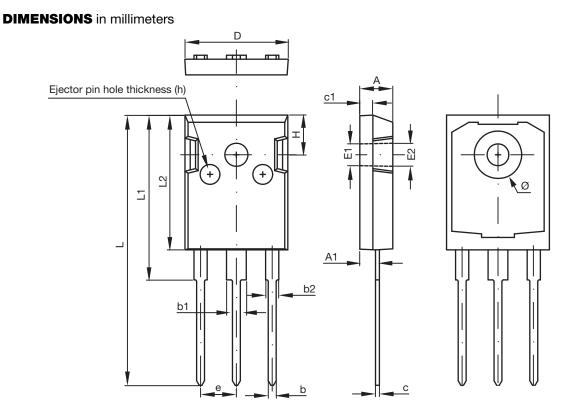
SYMBOL	DIMENSIONS	N MILLIMETERS	DIMENSION	S IN INCHES
STMDOL	MIN.	MAX.	MIN.	MAX.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 Ref.		0.138	3 Ref.
E2	3.60	00 Ref.	0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
е	10.900 Тур.		0.429 Тур.	
н	5.980 Тур.		0.235 Typ.	
h	0.000	0.300	0.000	0.012

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TO-247 3 Pin Long Lead



OVMDOL	DIMENSIONS	IN MILLIMETERS	DIMENSION	S IN INCHES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	
А	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	2.800	3.200	0.110	0.126	
b2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.50	00 Ref.	0.138 Ref.		
E2	3.60	00 Ref.	0.142	? Ref.	
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Ø	7.100	7.300	0.280	0.287	
е	5.450 Тур.		0.215	Тур.	
Н	5.980 Тур.		0.235 Typ.		
h	0.000	0.300	0.000	0.012	

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